

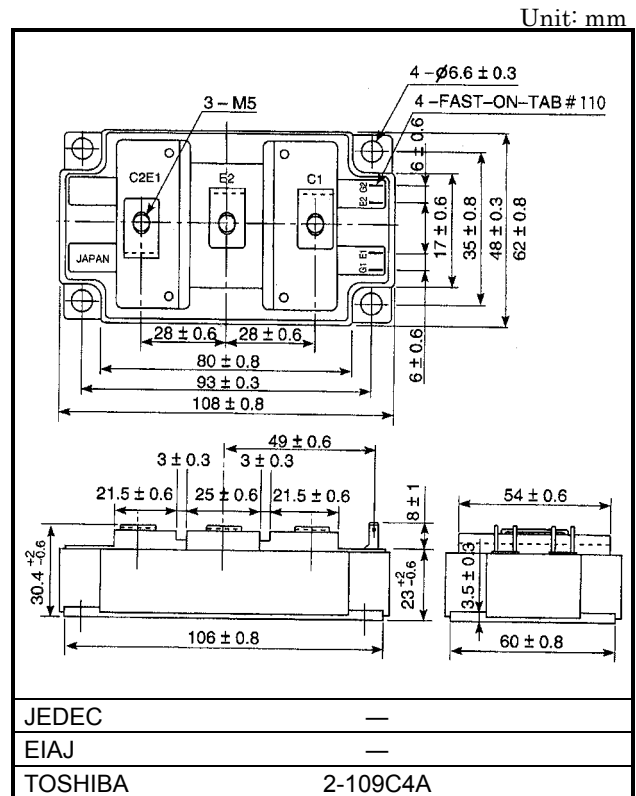
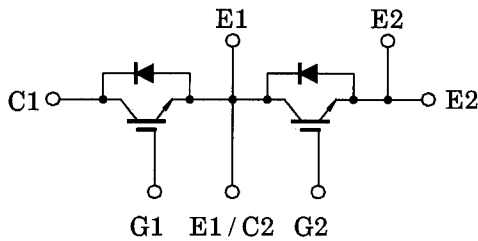
TOSHIBA GTR Module Silicon N Channel IGBT

# MG100Q2YS51

High Power Switching Applications  
Motor Control Applications

- High input impedance
- High speed :  $t_f = 0.3\mu s$  (Max)  
@Inductive load
- Low saturation voltage  
:  $V_{CE(sat)} = 3.6V$  (Max)
- Enhancement-mode
- Includes a complete half bridge in one package.
- The electrodes are isolated from case.

## Equivalent Circuit



Weight: 430g

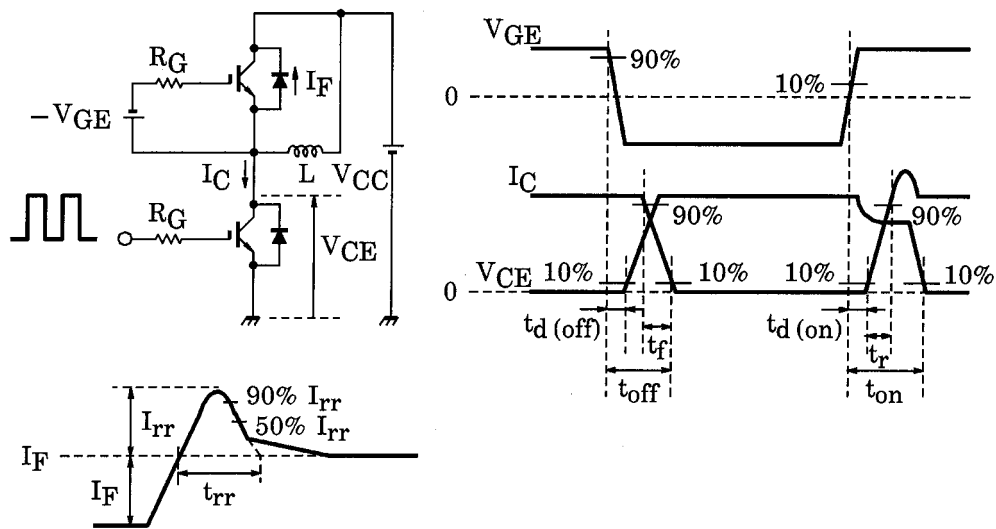
## Maximum Ratings (Ta = 25°C)

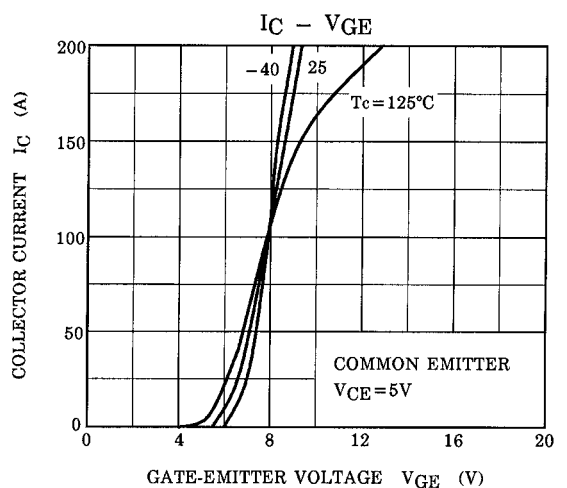
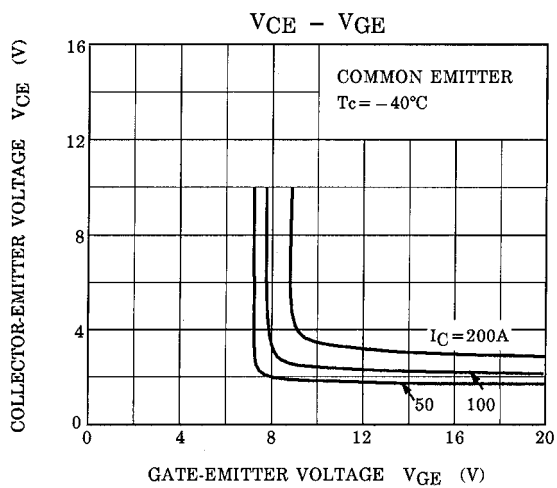
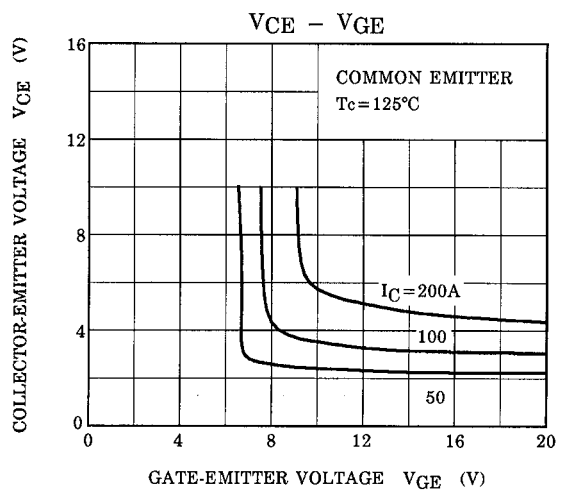
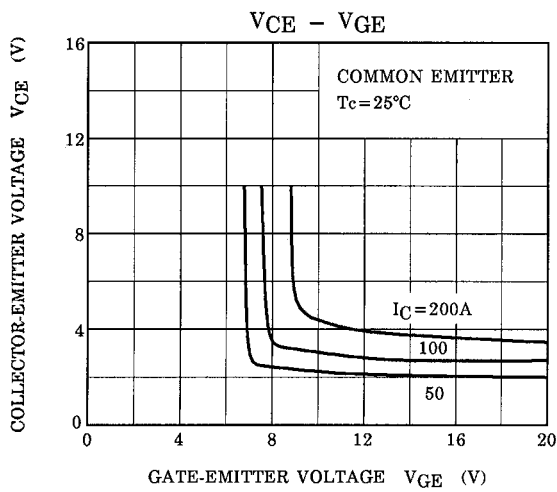
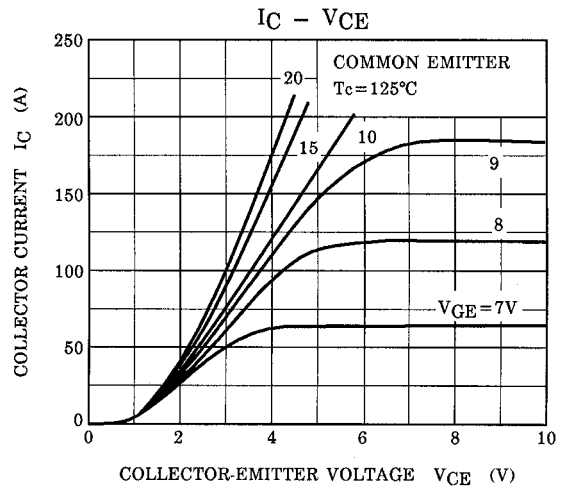
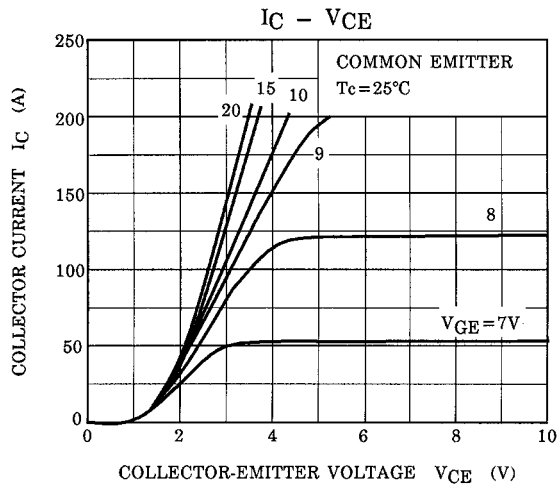
Characteristic	Symbol	Rating	Unit	
Collector-emitter voltage	$V_{CES}$	1200	V	
Gate-emitter voltage	$V_{GES}$	±20	V	
Collector current	DC	$I_C$ (25°C / 80°C)	150 / 100	A
	1ms	$I_{CP}$ (25°C / 80°C)	300 / 200	
Forward current	DC	$I_F$	100	A
	1ms	$I_{FM}$	200	
Collector power dissipation (Tc = 25°C)	$P_C$	660	W	
Junction temperature	$T_j$	150	°C	
Storage temperature range	$T_{stg}$	-40 ~ 125	°C	
Isolation voltage	$V_{Isol}$	2500 (AC 1 min.)	V	
Screw torque (Terminal / mounting)	—	3 / 3	N·m	

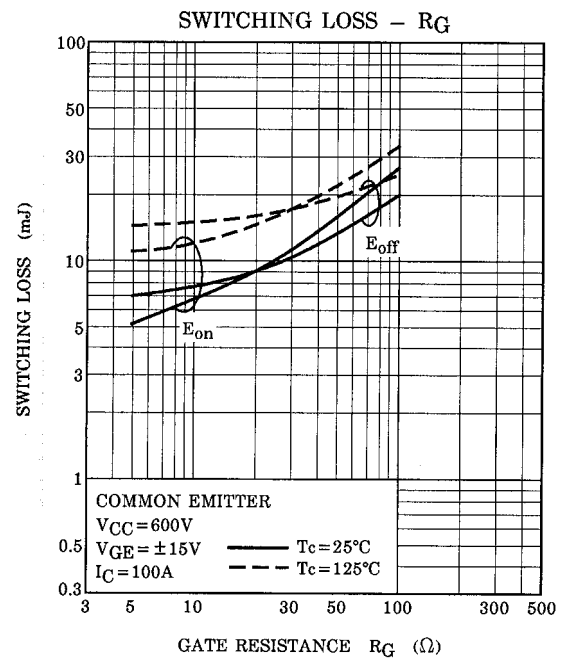
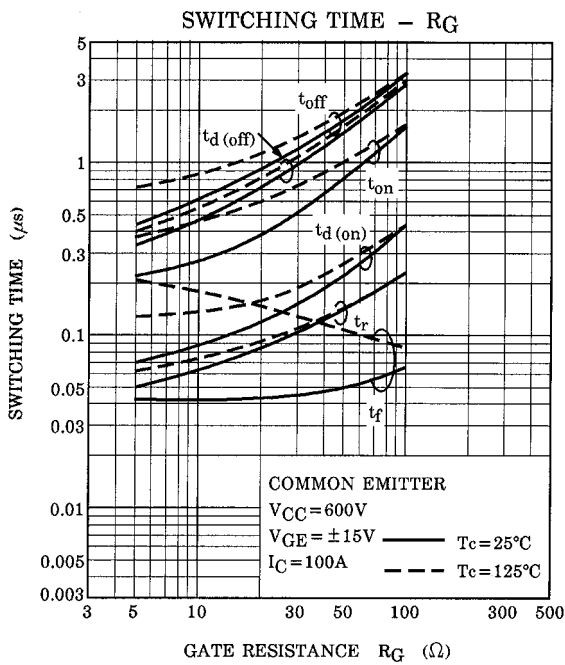
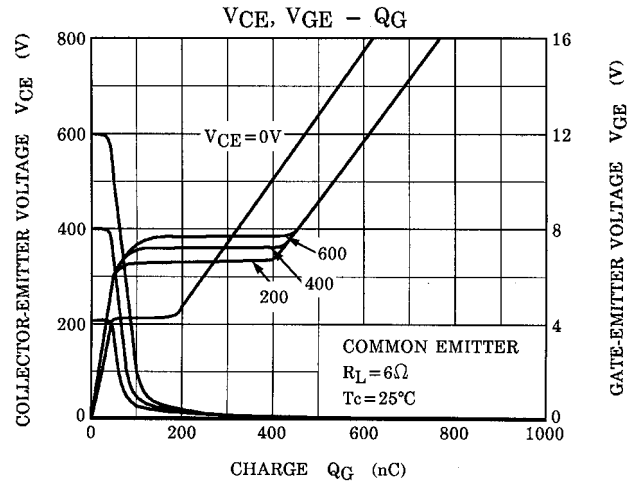
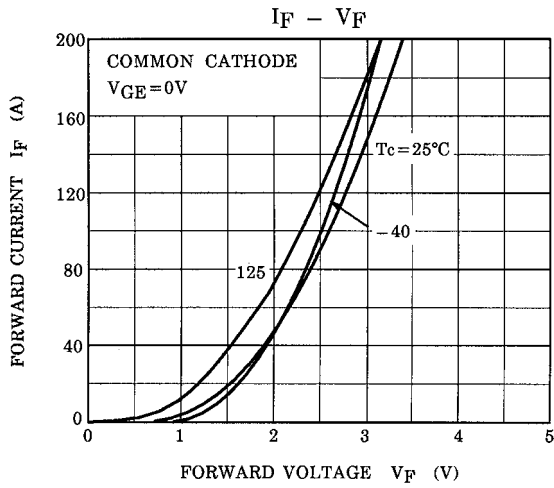
## Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit	
Gate leakage current	$I_{GES}$	$V_{GE} = \pm 20V, V_{CE} = 0$	—	—	$\pm 500$	nA	
Collector cut-off current	$I_{CES}$	$V_{CE} = 1200V, V_{GE} = 0$	—	—	2.0	mA	
Gate-emitter cut-off voltage	$V_{GE (off)}$	$I_C = 100mA, V_{CE} = 5A$	3.0	—	6.0	V	
Collector-emitter Saturation voltage	$V_{CE (sat)}$	$I_C = 100A, V_{GE} = 15V$	$T_j = 25^\circ C$	—	2.8	3.6	V
			$T_j = 125^\circ C$	—	3.1	4.0	
Input capacitance	$C_{ies}$	$V_{CE} = 10V, V_{GE} = 0, f = 1MHz$	—	12.0	—	nF	
Switching time	Turn-on delay time	$t_{d(on)}$	—	0.05	—	$\mu s$	
	Rise time	$t_r$	Inductive load $V_{CC} = 600V$ $I_C = 100A$ $V_{GE} = \pm 15V$ $R_G = 9.1\Omega$  (Note 1)	—	0.05		—
	Turn-on time	$t_{on}$		—	0.2		—
	Turn-off delay time	$t_{d(off)}$		—	0.5		—
	Fall time	$t_f$		—	0.1		0.3
	Turn-off time	$t_{off}$		—	0.6		—
Forward voltage	$V_F$	$I_F = 100A, V_{GE} = 0$		—	2.4	3.5	V
Reverse recovery time	$t_{rr}$	$I_F = 100A, V_{GE} = -10V$ $di / dt = 700A / \mu s$ (Note 1)	—	0.1	0.25	$\mu s$	
Thermal resistance	$R_{th (j-c)}$	Transistor stage	—	—	0.16	$^\circ C / W$	
		Diode stage	—	—	0.47		

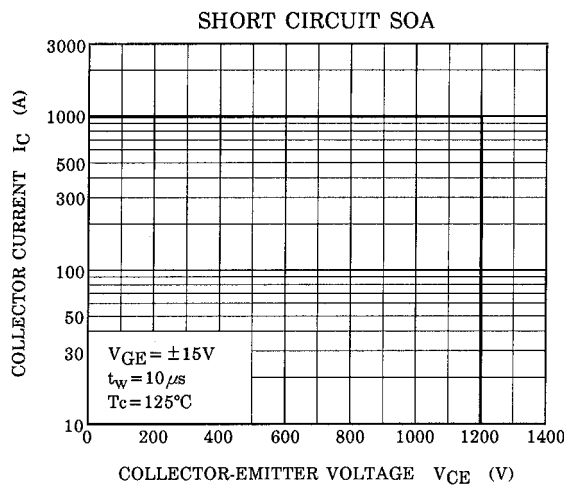
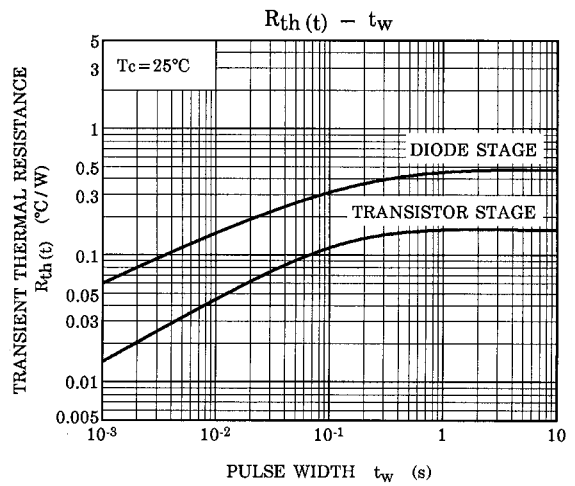
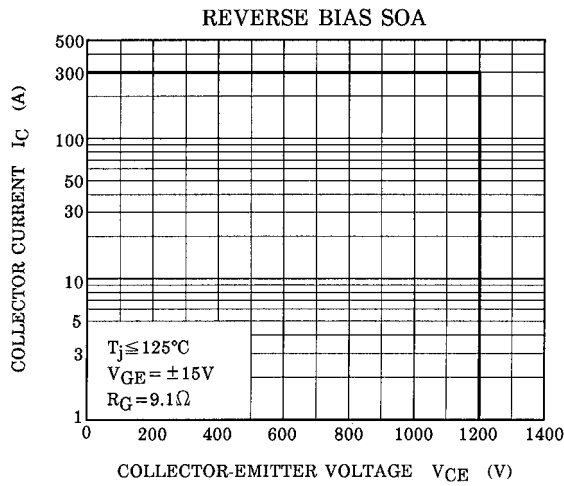
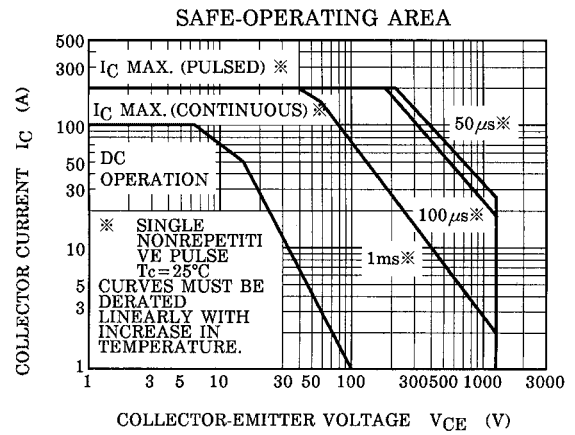
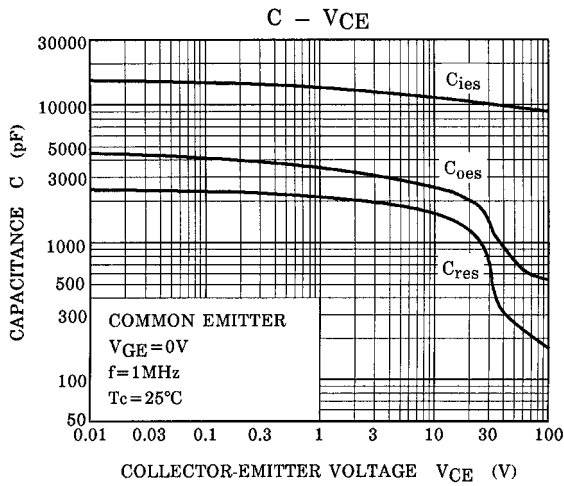
Note 1: Switching time and reverse recovery time test circuit & timing chart











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